

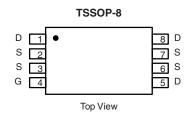
## **IRF7700GTRPBF-VB Datasheet** P-Channel 20-V (G-S) MOSFET

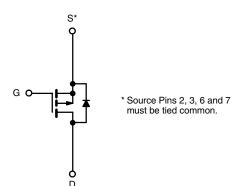
PRODUCT	SUMMARY	
V <sub>DS</sub> (V)	<b>R<sub>DS(on)</sub> (</b> Ω <b>)</b>	I <sub>D</sub> (A)
	0.010 at V <sub>GS</sub> = - 4.5 V	- 9.0
-20	0.012 at V <sub>GS</sub> = - 2.5 V	- 7.8
	0.016 at V <sub>GS</sub> = - 1.8 V	- 6.0

### **FEATURES**

- Halogen-free
- Trench Power MOSFETs •







P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS T	$_{\Lambda}$ = 25 °C, unles	ss otherwise no	oted		
Parameter		Symbol	10 s	Steady State	Unit
Drain-Source Voltage		V <sub>DS</sub>	-2	20	V
Gate-Source Voltage		V <sub>GS</sub>	±	: 12	v
	T <sub>A</sub> = 25 °C	1	- 9.0	-7.8	
Continuous Drain Current (T <sub>J</sub> = 150 °C) <sup>a</sup>	T <sub>A</sub> = 70 °C	- <sup>I</sup> D	- 6.8	-5.8	•
Pulsed Drain Current (10 µs Pulse Width)	·	I <sub>DM</sub>	- :	30	A
Continuous Source Current (Diode Conduction) <sup>a</sup>		۱ <sub>S</sub>	- 1.35	- 0.95	
	T <sub>A</sub> = 25 °C	PD	1.5	1.05	W
Maximum Power Dissipation <sup>a</sup>	T <sub>A</sub> = 70 °C	ГD	1.0	0.67	vv
Operating Junction and Storage Temperature Range	÷	T <sub>J</sub> , T <sub>stg</sub>	- 55 t	to 150	°C

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Manimum lumation to Ambianta	t ≤ 10 s	R <sub>thJA</sub>	65	83	
Maximum Junction-to-Ambient <sup>a</sup>	Steady State	' 'thJA	100	120	°C/W
Maximum Junction-to-Foot (Drain)	Steady State	R <sub>thJF</sub>	43	52	

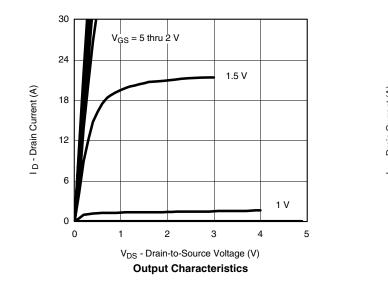
Notes: a. Surface Mounted on 1" x 1" FR4 board.

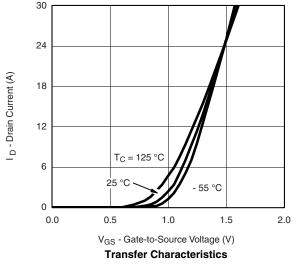
SPECIFICATIONS $T_J = 25$ °C	C, unless o	therwise noted					
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}$ , $I_D = -450 \ \mu A$	- 0.45	-	1.0	V	
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 V$ , $V_{GS} = \pm 8 V$			± 100	nA	
Zoro Coto Voltogo Droin Current	Inne	$V_{DS} = -20 V, V_{GS} = 0 V$			- 1		
Zero Gate Voltage Drain Current	IDSS	$V_{DS} = -20V, V_{GS} = 0 V, T_{J} = 70 \ ^{\circ}C$			- 25	μA	
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} = -5 V, V_{GS} = -4.5 V$	- 20			А	
		$V_{GS} = -4.5 \text{ V}, I_D = -8.0 \text{ A}$		0.010			
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> = - 2.5 V, I <sub>D</sub> = - 7.0 A		0.012		Ω	
		V <sub>GS</sub> = - 1.8 V, I <sub>D</sub> = - 5.8 A		0.016		l	
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = - 5 V, I <sub>D</sub> = - 8.0 A		44		S	
Diode Forward Voltage <sup>a</sup>	V <sub>SD</sub>	I <sub>S</sub> = - 1.5 A, V <sub>GS</sub> = 0 V		- 0.56	- 1.1	V	
Dynamic <sup>b</sup>							
Total Gate Charge	Qg			46	70		
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}$ = - 10 V, $V_{GS}$ = - 4.5 V, $I_D$ = - 8.0 A	5		nC		
Gate-Drain Charge	Q <sub>gd</sub>			15.5			
Turn-On Delay Time	t <sub>d(on)</sub>			45	70		
Rise Time	t <sub>r</sub>	V <sub>DD</sub> = - 10 V, <u></u> = 6 Ω		85	130		
Turn-Off Delay Time	t <sub>d(off)</sub>	${\sf I}_{\sf D}\cong$ - 1 A, ${\sf V}_{\sf GEN}$ = - 4.5 V, ${\sf R}_{\sf g}$ = 6 $\Omega$		220	400	ns	
Fall Time	t <sub>f</sub>			155	235		
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = - 1.5 A, di/dt = 100 A/μs		140	210		

Notes: a. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %. b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

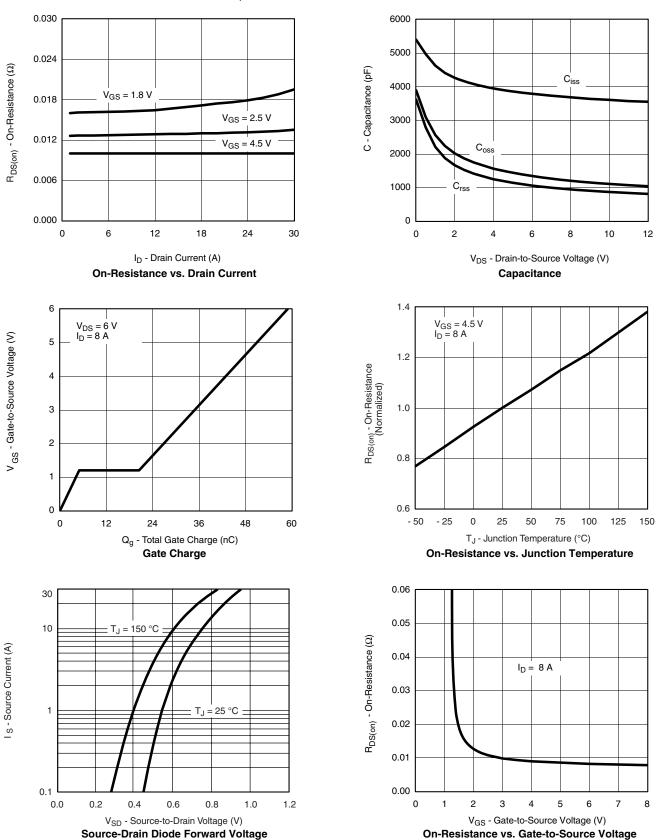




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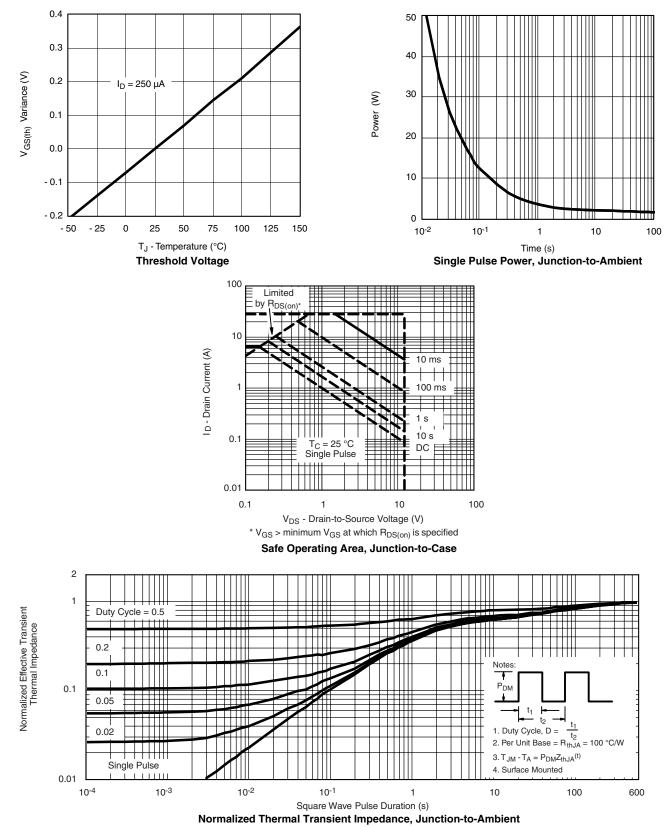
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服务热线:400-655-8788

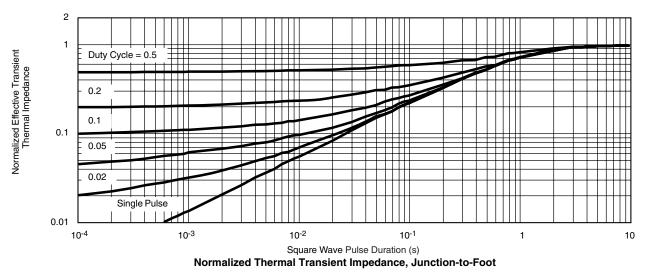


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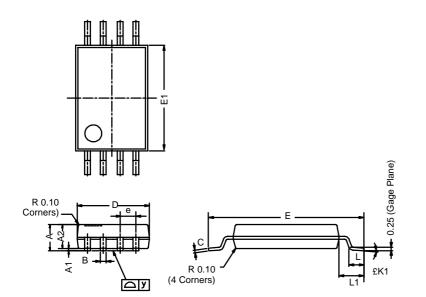


### IRF7700GTRPBF-VB



### TSSOP: 8-LEAD

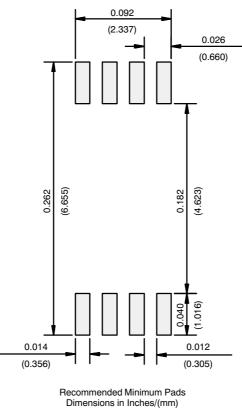
JEDEC Part Number: MO-153



Dim	MILLIMETERS				
	Min	Nom	Max		
Α	-	-	1.20		
<b>A</b> <sub>1</sub>	0.05	0.10	0.15		
A <sub>2</sub>	0.80	1.00	1.05		
В	0.19	0.28	0.30		
С	-	0.127	-		
D	2.90	3.00	3.10		
Е	6.20	6.40	6.60		
E <sub>1</sub>	4.30	4.40	4.50		
е	-	0.65	-		
L	0.45	0.60	0.75		
L <sub>1</sub>	0.90	1.00	1.10		
Y	-	-	0.10		
£ <b>K1</b>	0°	3°	6°		



### **RECOMMENDED MINIMUM PADS FOR TSSOP-8**





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